

Product Overview

The CMD324 is negative controlled, wideband GaAs MMIC 2-bit digital attenuator die which operates from DC to 30 GHz. Each bit of the attenuator is controlled by a single voltage of either 0 V or -5 V. The attenuator bit values are 10 dB and 20 dB, for a total attenuation of 30 dB. The CMD324 has a low insertion loss of 2.9 dB at 15 GHz and the attenuation accuracy is typically less than 10 % step error. The CMD324 is a 50 ohm matched design which eliminates the need for RF port matching. The CMD324 offers full passivation for increased reliability and moisture protection.

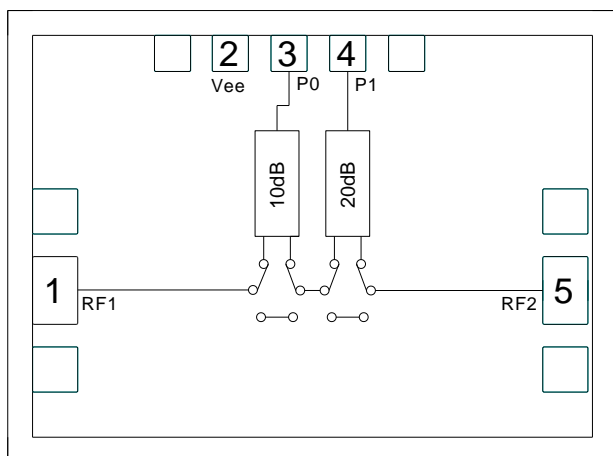
Key Features

- Ultra Wideband Performance
- Low Insertion Loss
- Wide Attenuation Range
- Small Die Size

Ordering Information

Part No.	Description
CMD324	25 pcs WP, 100 pcs MOQ

Functional Block Diagram



Electrical Performance ($V_{ee} = -5\text{ V}$, $V_{ctl} = 0/-5\text{ V}$, $T_A = 25^\circ\text{ C}$, $F = 15\text{ GHz}$)

Parameter	Min	Typ	Max	Units
Frequency Range		DC - 30		GHz
Insertion Loss		2.9		dB
Attenuation Range		30		dB
Input Return Loss		15		dB
Output Return Loss		13		dB
Input P1dB		24		dBm
Input IP3		36		dBm
Switching Speed		28		ns

Absolute Maximum Ratings

Parameter	Rating
Bias Voltage, V_{ee}	-8 V
Control Voltage, V_{ctl}	-8 V
RF Input Power	+26.6 dBm
Thermal Resistance, Q_{JC}	140° C/W
Operating Temperature	-55 to 85° C
Storage Temperature	-55 to 150° C

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

Truth Table

Control Voltage Input		Attenuation State RF1-RF2 (dB)
P0 10 dB	P1 20 dB	
Low	Low	Reference (insertion loss)
High	Low	10
Low	High	20
High	High	30

Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
V_{ee}	-5.5	-5	-2.5	V

Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

Control Voltage

State	Bias Condition
High	$V_{ee} \pm 0.3$ V
Low	0 ± 0.3 V

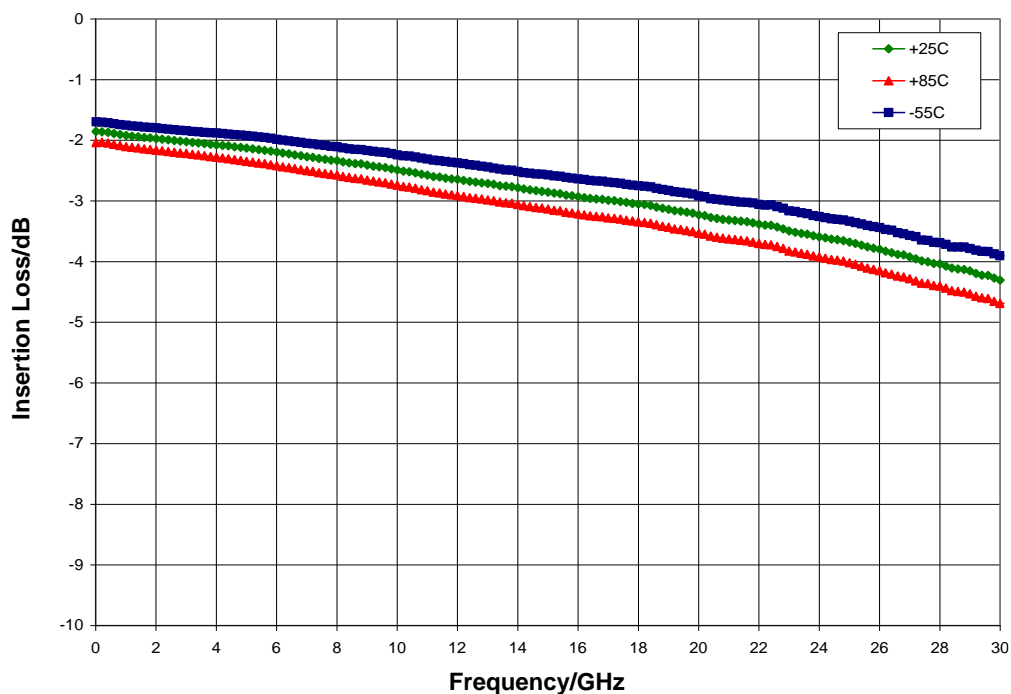
Electrical Specifications ($V_{ee} = -5$ V, $V_{ctl} = 0/-5$ V, $T_A = 25^\circ$ C)

Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range	DC - 15			15 - 30			GHz
Insertion Loss		2.3	3.4		3.4	4.8	dB
Attenuation Range		30			30		dB
Attenuation Accuracy	$\pm 0.5 + 10\%$ of Atten. Setting Max			$\pm 0.5 + 8\%$ of Atten. Setting Max			dB
Input Return Loss		15			15		dB
Output Return Loss		13			13		dB
Input P1dB		25			24		dBm
Input IP3		37			38		dBm

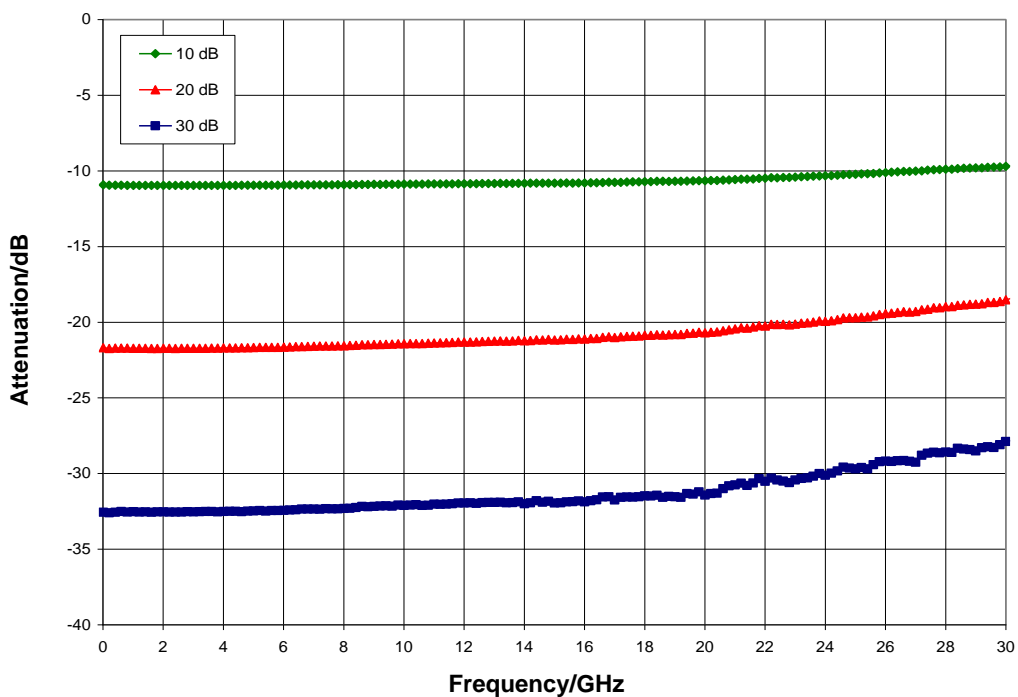
Note: Specification applies to major states

Typical Performance

Insertion Loss versus Temperature

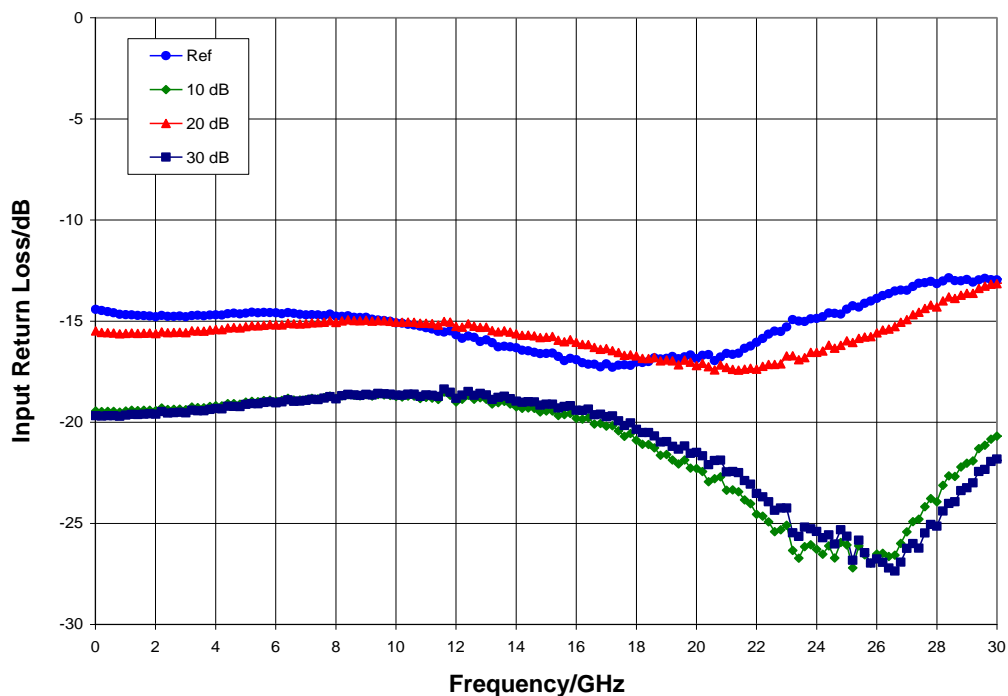


Normalized Attenuation (all states), $T_A = 25^\circ\text{C}$

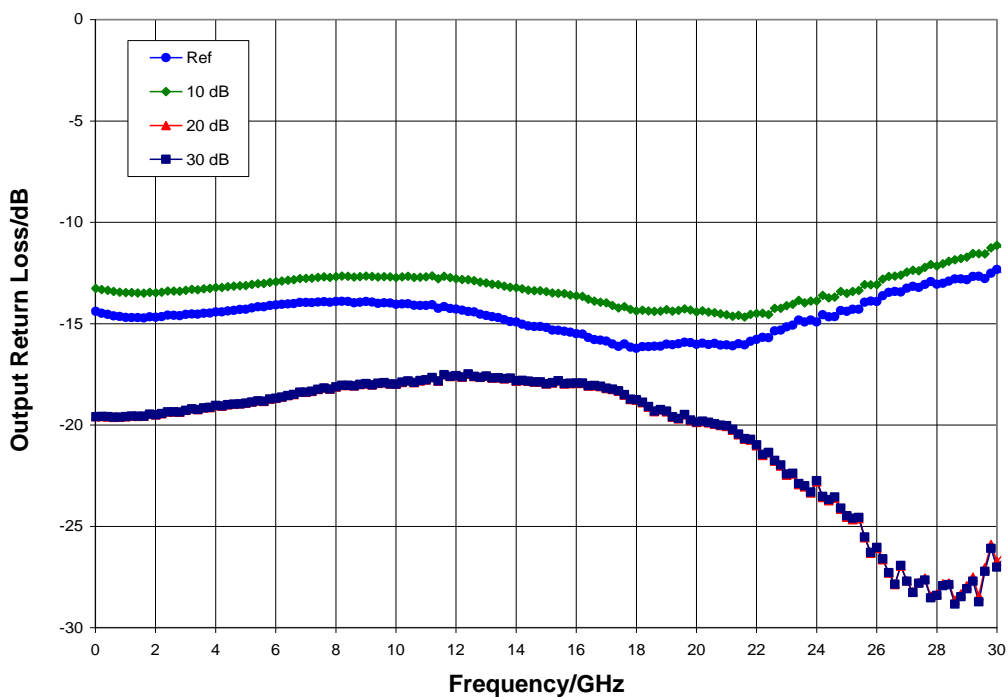


Typical Performance

Input Return Loss (all states), $T_A = 25^\circ\text{C}$

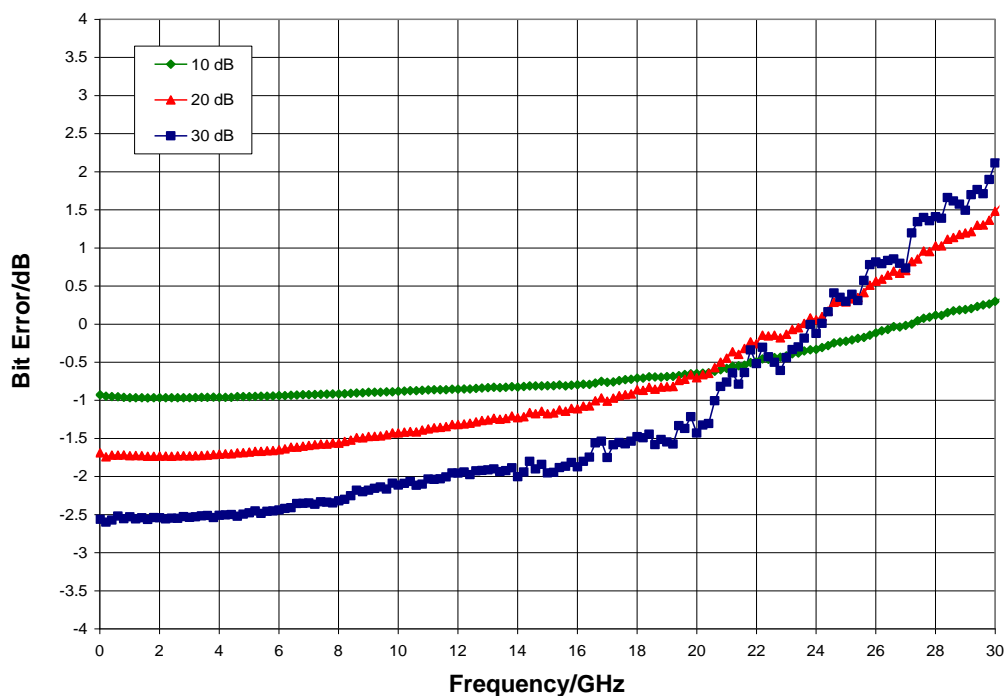


Output Return Loss (all states), $T_A = 25^\circ\text{C}$

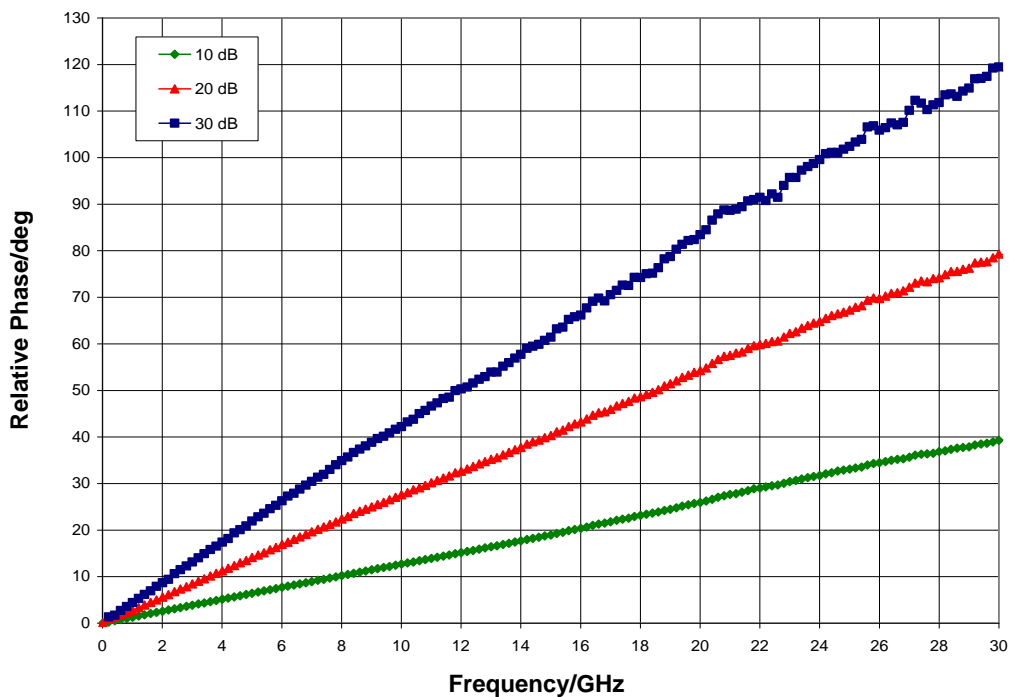


Typical Performance

Bit Error versus Frequency, $T_A = 25^\circ\text{C}$

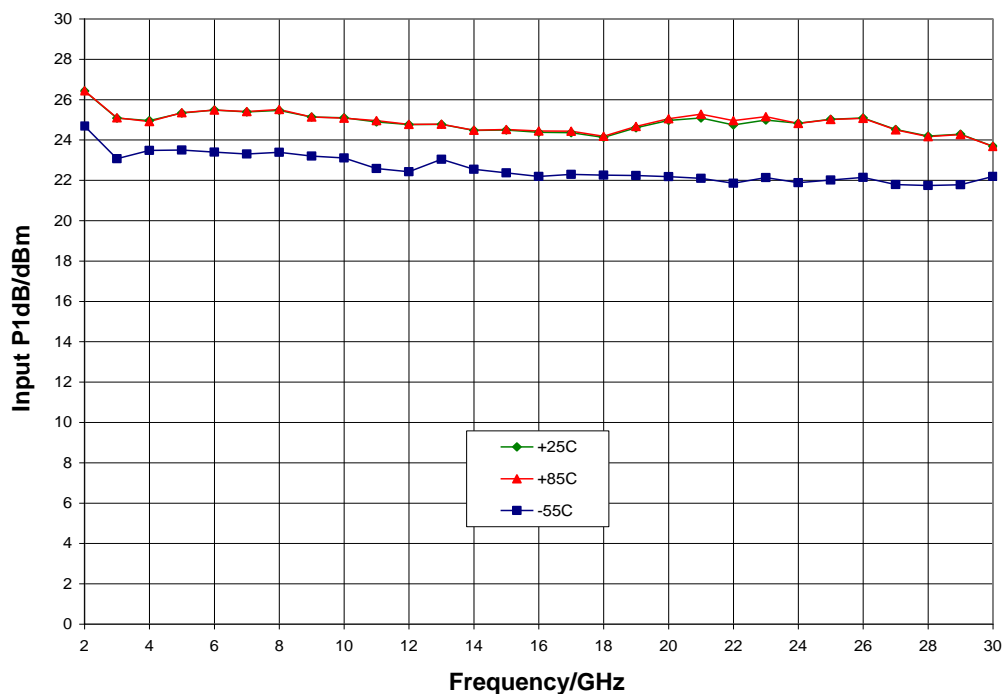


Relative Phase versus Frequency, $T_A = 25^\circ\text{C}$

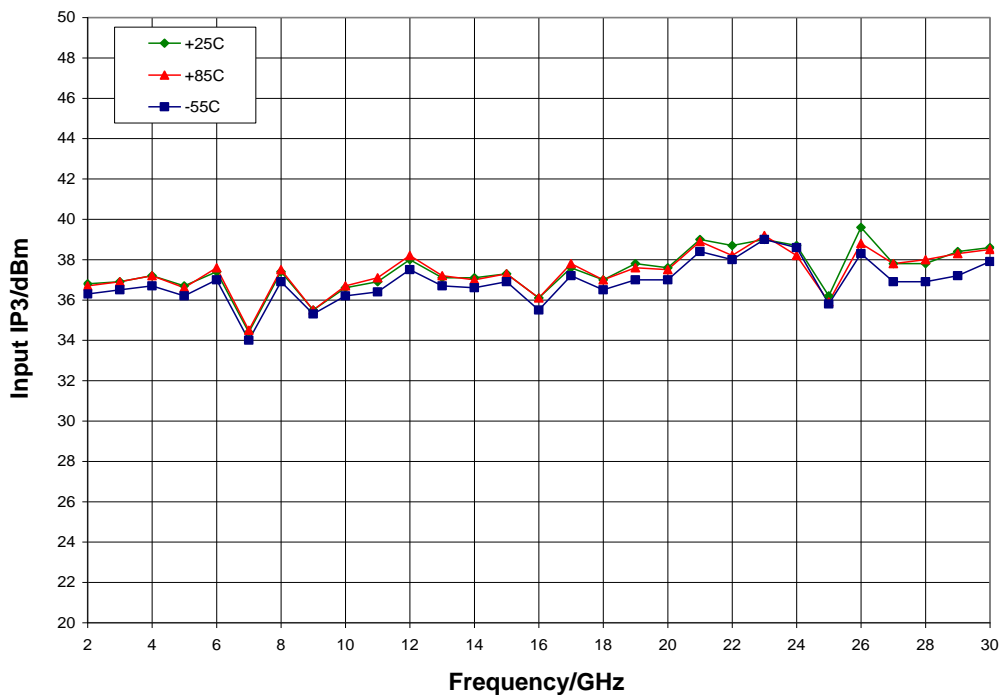


Typical Performance

Input Power for 1 dB Compression (insertion loss state)

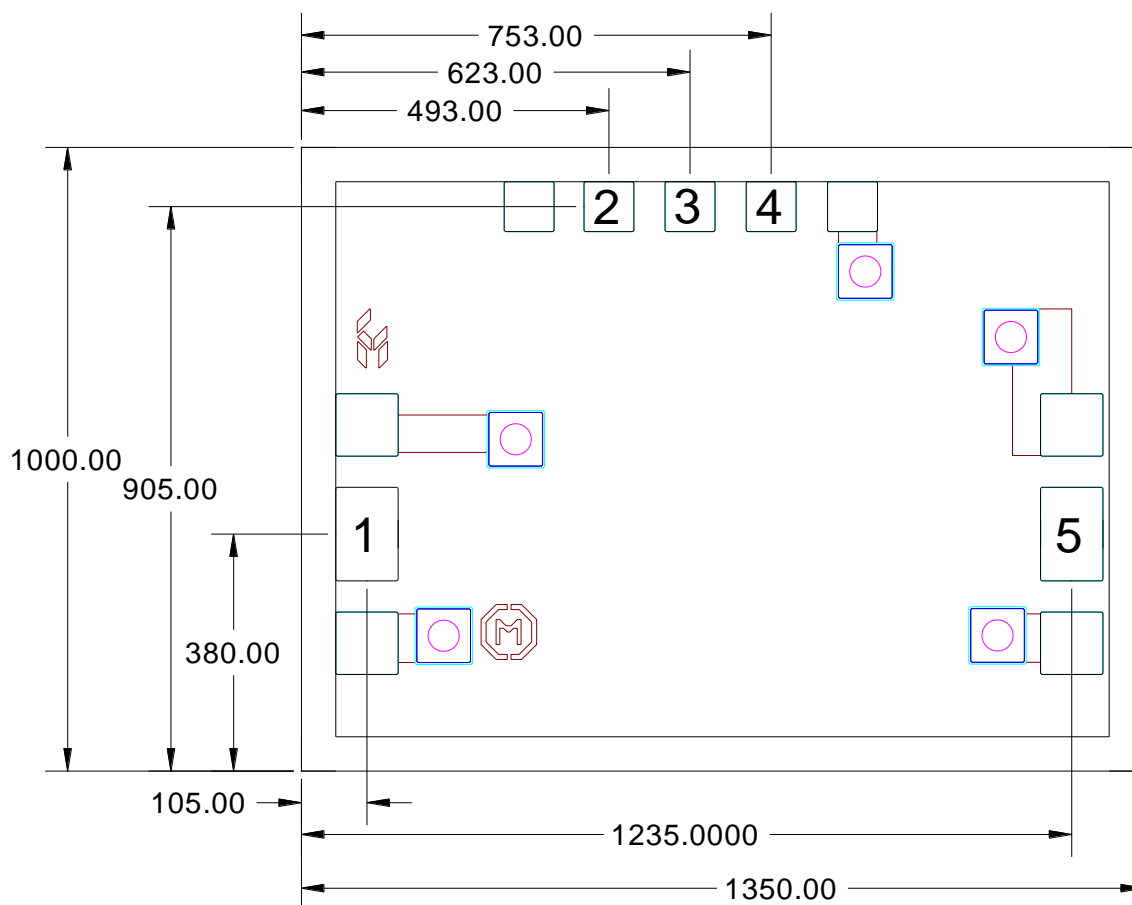


Input IP3 versus Temperature (insertion loss state)



Mechanical Information

Die Outline (all dimensions in microns)

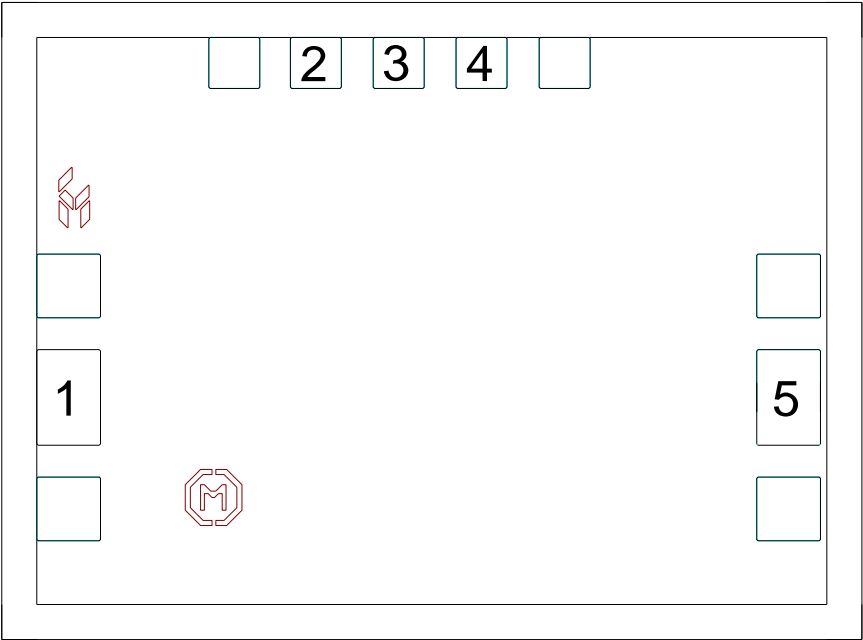


Notes:

1. No connection required for unlabeled pads
2. Backside is RF and DC ground
3. Backside and bond pad metal: Gold
4. Die is 100 microns thick
5. DC bond pads (2, 3, 4) are 80 x 80 microns square
6. RF bond pads (1, 5) are 100 x 150 microns

Pad Description

Pad Diagram



Functional Description

Pad	Function	Description	Schematic
1, 5	RF1, RF2	These pins are DC coupled and matched to 50 ohm Blocking capacitors are required if RF line potential is not equal to 0 V	
2	V _{ee}	Negative bias -5 V	
3, 4	P0, P1	Bit control voltages, see truth table for values	
Backside	Ground	Connect to RF / DC ground	

Applications Information

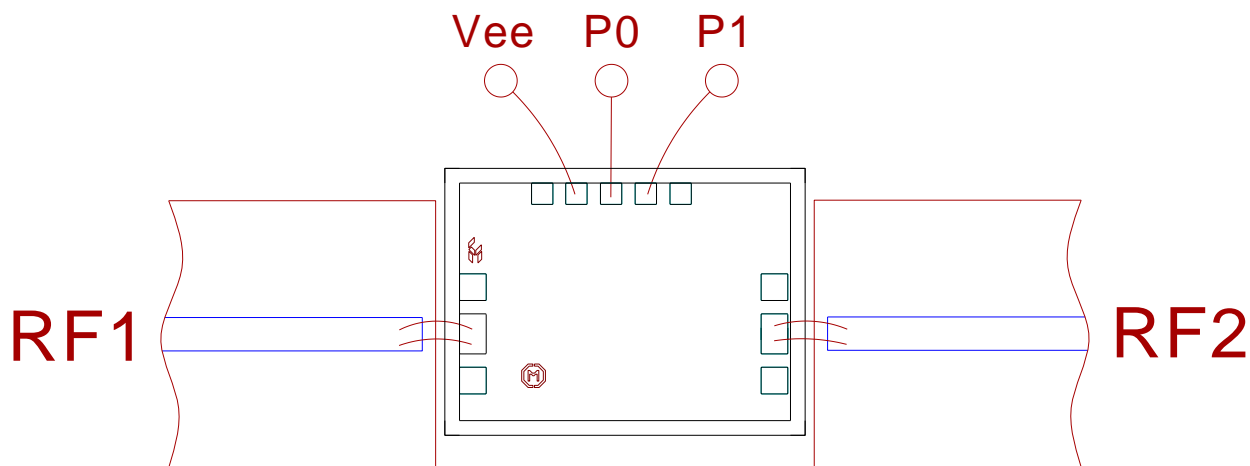
Assembly Guidelines

The backside of the CMD324 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines, and the RF decoupling capacitors placed in close proximity to the DC connections on chip.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized. The RF input and output require a single bond wire as shown.

The semiconductor is 100 μm thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram



Biasing and Operation

The CMD324 has two control lines and a V_{ee} bias port. The CMD324 will not operate unless V_{ee} is applied to the MMIC.

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A ($C_{15}H_{12}Br_4O_2$) Free
- SVHC Free
- PFOS Free
- Halogen Free



Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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